## 國立成功大學九十四學年度碩士班招生考試試題

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編號: 116 系所:電機工程學系甲組

科目:電子材料概論

- 1. Please explain following noun: (15%)
  - a). Schottky defect
  - b). Frankel defect
  - c). Burgers vector
  - d). Eutectic reaction
  - e). Peritectic reaction
- 2. Copper(ion radius=0.125nm) and nickel (ion radius= 0.128nm) form a solid solution in all properties. Predict this result using the Hume-Rothery rules (15%)
- 3. Calculate the theoretical density of CsCl. (20%)
  ( atomic weight of Cs and Cl are 132.9g/mol and 35.45g/mol, r(Cs<sup>+</sup>)=0.167nm and r(Cl<sup>-</sup>)=0.181nm,
  Avogadro's number =6.023x10<sup>23</sup> atom/mol)
- 4. Explain or define the following terms. (20%)
  - a). Skin effect
  - b). Fluorescence (螢光)
  - c). No Center of Symmetry
  - d). Loss Tangent
- 5. A typical 1 MHz quartz crystal has the following properties:  $f_s = 1$  MHz,  $f_a = 1.0025$  MHz,  $C_o = 5$  pF,  $R = 20 \Omega$  What are C and L in the equivalent circuit of the quartz? What is the quality factor of the crystal, given that  $Q = \frac{1}{2\pi f_s RC}$ ? (15%)
- 6. When the dielectric fills the whole space between the plates of a capacitor, the net field within the dielectric is the same as before, E = V/d. Explain what happens when a dielectric slab of thickness  $t \ll d$  is inserted in the middle of the space between the plates, as shown in Fig. 1. What is the field inside the dielectric? (15%)

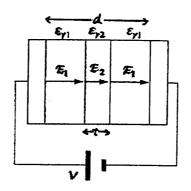


Fig. 1